TOSHIBA

TOSHIBA Field Effect Transistor Silicon P Channel MOS Type

SSM5P15FU

High Speed Switching Applications

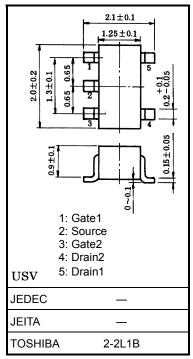
Analog Switch Applications

- Small package
- Low ON resistance : $R_{on} = 12 \Omega (max) (@V_{GS} = -4 V)$: $R_{on} = 32 \Omega (max) (@V_{GS} = -2.5 V)$

Maximum Ratings (Ta = 25°C) (Q1, Q2 Common)

Characteristics		Symbol	Rating	Unit	
Drain-Source voltage		V _{DS}	-30	V	
Gate-Source voltage		V _{GSS}	±20	V	
Drain current	DC	I _D	-100	mA	
	Pulse	I _{DP}	-200		
Drain power dissipation (Ta = 25°C)		P _{D (Note)}	200	mW	
Channel temperature		T _{ch}	150	°C	
Storage temperature range		T _{stg}	-55~150	°C	

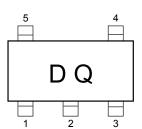
Note: Total rating.

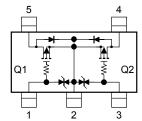


Weight: 0.006g(typ.)

Marking







Handling Precaution

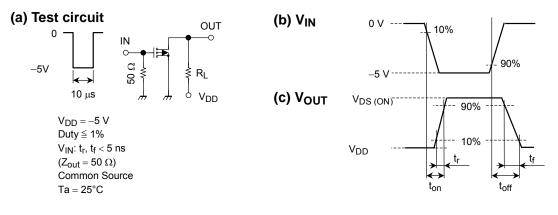
When handling individual devices (which are not yet mounting on a circuit board), be sure that the environment is protected against electrostatic electricity. Operators should wear anti-static clothing, and containers and other objects that come into direct contact with devices should be made of anti-static materials.

Unit: mm

Electrical Characteristics (Ta = 25°C) (Q1, Q2 common)

Characteristic		Symbol	Test Condition	MIN.	TYP.	MAX.	UNIT
Gate leakage current		I _{GSS}	$V_{GS} = \pm 16 V, V_{DS} = 0$	_		±1	μA
Drain-Source breakdown voltage		V (BR) DSS	$I_D = -0.1 \text{ mA}, V_{GS} = 0$	-30		_	V
Drain cut-off current		I _{DSS}	$V_{DS} = -30 \text{ V}, \text{ V}_{GS} = 0$	_		-1	μA
Gate threshold voltage		V _{th}	$V_{DS} = -3 V$, $I_{D} = -0.1 mA$	-1.1		-1.7	V
Forward transfer admittance		Y _{fs}	$V_{DS} = -3 V$, $I_{D} = -10 mA$	20		—	mS
Drain-Source ON resistance		R _{DS (ON)}	$I_D = -10$ mA, $V_{GS} = -4$ V	_	8	12	Ω
			$I_D = -1 \text{ mA}, V_{GS} = -2.5 \text{ V}$	_	14	32	
Input capacitance		C _{iss}	$V_{DS} = -3 \text{ V}, \text{ V}_{GS} = 0, \text{ f} = 1 \text{ MHz}$	_	9.1	_	pF
Reverse transfer capacitance		C _{rss}		_	3.5	—	pF
Output capacitance		C _{oss}	-	_	8.6	—	pF
Switching time	Turn-on time	t _{on}	$V_{DD} = -5 \text{ V}, \text{ I}_{D} = -10 \text{ mA}, V_{GS} = 0 \text{~}-5 \text{ V}$	—	65	—	ns
	Turn-off time	t _{off}			175	—	

Switching Time Test Circuit

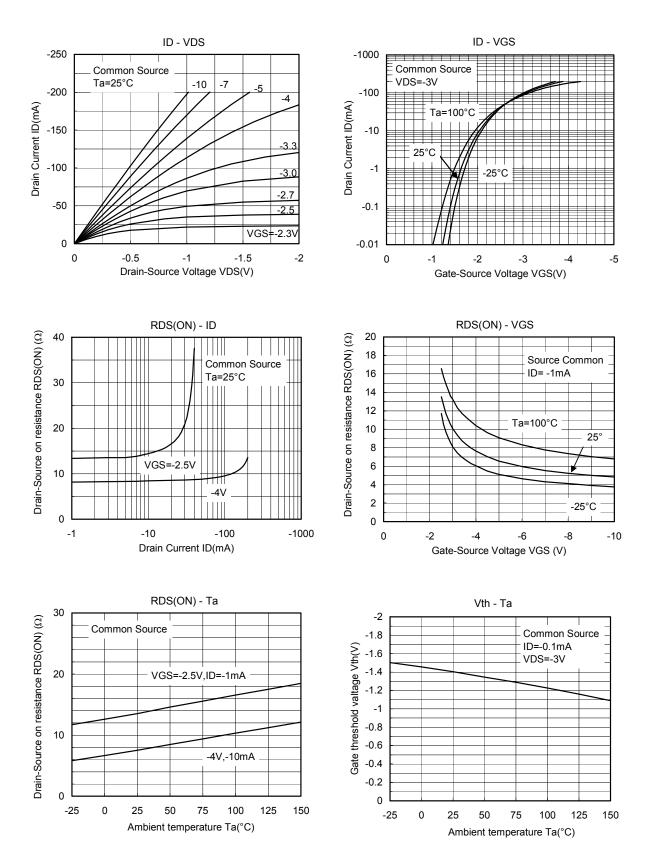


Precaution

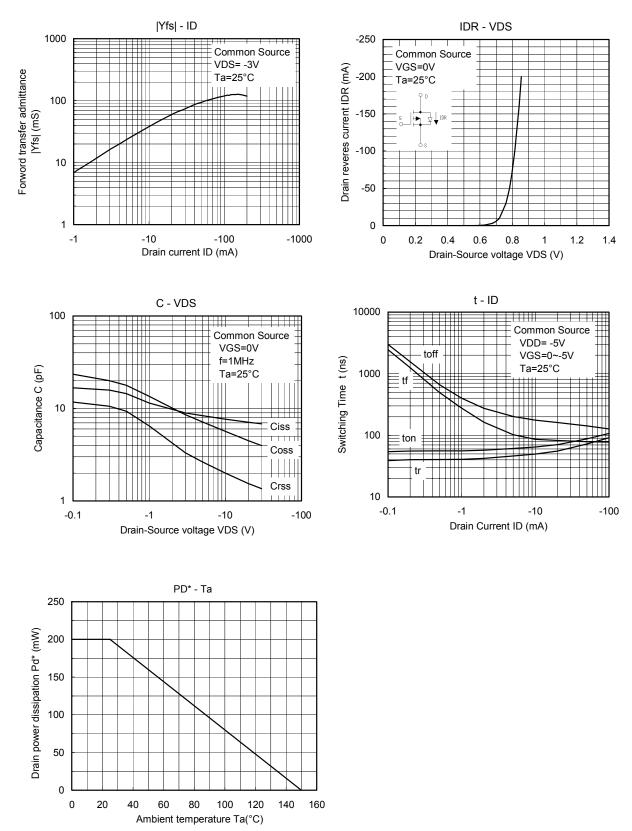
 V_{th} can be expressed as voltage between gate and source when low operating current value is $I_D = -100 \ \mu A$ for this product. For normal switching operation, V_{GS} (on) requires higher voltage than V_{th} and V_{GS} (off) requires lower voltage than V_{th} . (Relationship can be established as follows: V_{GS} (off) $< V_{th} < V_{GS}$ (on))

Please take this into consideration for using the device. V_{GS} recommended voltage of -2.5 V or higher to turn on this product.

TOSHIBA



TOSHIBA



*: Total Rating

RESTRICTIONS ON PRODUCT USE

030619EAA

- The information contained herein is subject to change without notice.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA for any infringements of patents or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of TOSHIBA or others.
- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and
- set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- TOSHIBA products should not be embedded to the downstream products which are prohibited to be produced and sold, under any law and regulations.